

53 dB Gain High Power GaN Amplifier at 200 Watt Psat Operating from 1 GHz to 2 GHz with SMA Input, Type N Output

The FMAM5063 is a high power amplifier that operates from 1 GHz to 2 GHz and generates 200 watts of saturated output power. The module utilizes GaN and chip-and-wire technology in the manufacturing process that ensures state-of-the-art power performance with excellent power-to-volume ratio that's ideal for broadband high power linear applications. This Class AB amplifier is designed for a 50 ohm input/output impedance and offers high efficiency and high linearity, operating over a wide dynamic range with impressive typical performance that includes 53 dB gain, 30% power added efficiency, ± 1.5 dB gain flatness, -20 dBc harmonic suppression, -60 dBc Spurious, and a maximum input power level of +10 dBm. Typical DC bias requirements include +28V and 20A of current. The module uses an SMA female input and a N type output connector. The DC interface incorporates a Hybrid D-Sub 7 pin male connector for DC bias, Enable with TTL logic control, Current Sense, and Temperature Sense functions. A mating female D-SUB socket connector is included. The rugged amplifier design operates over wide temperature range from -20°C and +55°C and can withstand relative humidity exposure up to 95% maximum. An available heatsink with cooling fan (model PE15G5068F) is recommended to maintain an optimum baseplate temperature during operation.



Features:

- GaN Design
- 1 GHz to 2 GHz Frequency Range
- Psat 200 Watts typ
- Power Gain: 53 dB typ
- Power Added Efficiency: 30%
- Gain Flatness ± 1.5 dB typ
- Enable with TTL Logic Control
- Current and Temperature Sense Functions
- 50 Ohms Input and Output Matched
- Low Distortion
- High Efficiency
- Class AB
- D-Sub Control Connector with Mating Female Connector
- Optional Heatsink Available: Model FMAMG5068F

Electrical Specifications

(TA = +25°C, DC Voltage = 28Volts , DC Current = 20A)

Description	Min	Typ	Max	Unit
Frequency Range	1		2	GHz
Small Signal Gain		53		dB
Gain Flatness		± 1.5		dB
Psat		+53		dBm
Efficiency (PAE)		30		%
Harmonics @150 Watts		-20		dBc
Spurious @150 Watts		-60		dBc
Impedance (Input)		50		Ohms
Impedance (Output)		50		Ohms
Input VSWR			3:1	
Input Return Loss			-10	dB
OFF/ON Switch Time (10% to 90%)		2	4	μ s
Operating DC Voltage	24	28	32	Volts
Operating DC Current @200 Watts		20		A
Operating Temperature Range	-20		+55	°C

Electrical Specification Notes: Allow for 20% Increased DC Current during initial power-up stage

Applications:

- Military Radio
- Communication Systems
- High Gain Driver Power Amplifier
- High Gain Output Power Amplifier
- Test and Measurement applications

Fairview Microwave
 301 Leora Ln., Suite 100
 Lewisville, TX 75056
 Tel: 1-800-715-4396 / (972) 649-6678
 Fax: (972) 649-6689
www.fairviewmicrowave.com
sales@fairviewmicrowave.com

Absolute Maximum Rating

Parameter	Rating
Input RF drive level without damage	+10 dBm (MAX)
Load VSWR @ Pout = 150 W	∞ @ all load phase & amplitude for duration of 1 minute; 3:1 @ all load phase & amplitude continuous
Over Temperature	85°C @ heatsink [restored @ 60°C]



ESD Sensitive Material,
Transport material in
Approved ESD bags. Handle
only in approved
ESD Workstation.

Mechanical Specifications

Size

Length	7.87 in [199.9 mm]
Width	5.9 in [149.86 mm]
Height	0.98 in [24.89 mm]
Weight	3.19 lbs [1.45 kg]
Input Connector	SMA Female
Output Connector	N Female
Bias Connector	Hybrid 7-Pin D-Subminiature Male

Environmental Specifications

Temperature

Operating Range	-20 to +55 deg C
Storage Range	-25 to +65 deg C
Humidity	95% Non-Condensing
Shock	Normal Truck Transport
Vibration	Normal Truck Transport

Compliance Certifications (see [product page](#) for current document)

Plotted and Other Data

Notes:

- Values at 25 °C, sea level
- Heatsink Required for Proper Operation Recommended Model: FMAMG5068F

Amplifier Power-up Precautions

- 1.) Confirm that proper ESD precautions and controls are always in place before handling any Amplifier module.
- 2.) Confirm adequate thermal management is in place to effectively dissipate heat away from the Amplifier package. The Amplifier operational baseplate temperature must be within the operational temperature range stated in the Amplifier datasheet. Depending on the design and thermal requirements, using a heatsink with cooling fan is always recommended for safe reliable operation. A heat sink without a cooling fan may also be used. Damage caused from overheating will void the warranty.
- 3.) Confirm adequate system grounding is established. The DC power supply and Amplifier must have a common ground in order to operate properly.
- 4.) Power Amplifiers may require additional DC Current when initially powered-up. Depending on the design, the input current draw could range from an additional 10% to 100% above the maximum rated DC current of the Amplifier. This varies based on product part number.
- 5.) Confirm the DC power supply, if limited, is set to allow for additional start-up current that's rated for the Power Amplifier.
- 6.) Confirm the system is designed and calibrated for 50 ohms. Any impedance mismatch may cause performance issues.
- 7.) Perform a CALIBRATION (if required) with the loads before connecting the Amplifier to the Network Analyzer to ensure proper performance.
- 8.) Use a fixed attenuator between the signal source and input port of the Amplifier to optimize the input VSWR match.
- 9.) Confirm the input power level at the input port of the amplifier does not exceed the maximum rated limit for input power (as stated in the Amplifier datasheet).
 P_{in} for Small Signal Gain = P1dB-SSG-10 dB
 P_{in} for P1dB = P1dB-SSG+1 dB
- 10.) Confirm the Network Analyzer is always connected to the Amplifier first before DC power is applied to the Amplifier.
- 11.) As long as the input and output ports of the amplifier are connected to a 50ohm load and RF signal power is applied, the Amplifier can be powered up with DC voltage.
- 12.) Confirm the Amplifier output load is matched for a 50 Ohm impedance and will not exceed the maximum rated VSWR or Return Loss limit for the Amplifier. Exceeding the maximum rated VSWR or Return Loss limit will result in reflected signal power that could damage the Amplifier and void the warranty.
- 13.) **Power Amplifier connected to an Antenna for signal transmission** - It's strongly recommended to use a high power fixed attenuator pad or an Isolator between the output port of the Amplifier and input port to the antenna. Any reflected signal power due to impedance mismatch will likely damage the Amplifier and void the warranty.
- 14.) The attenuator or isolator used at the output port of the Amplifier must be rated to handle the output power level and operational frequency band of the amplifier.

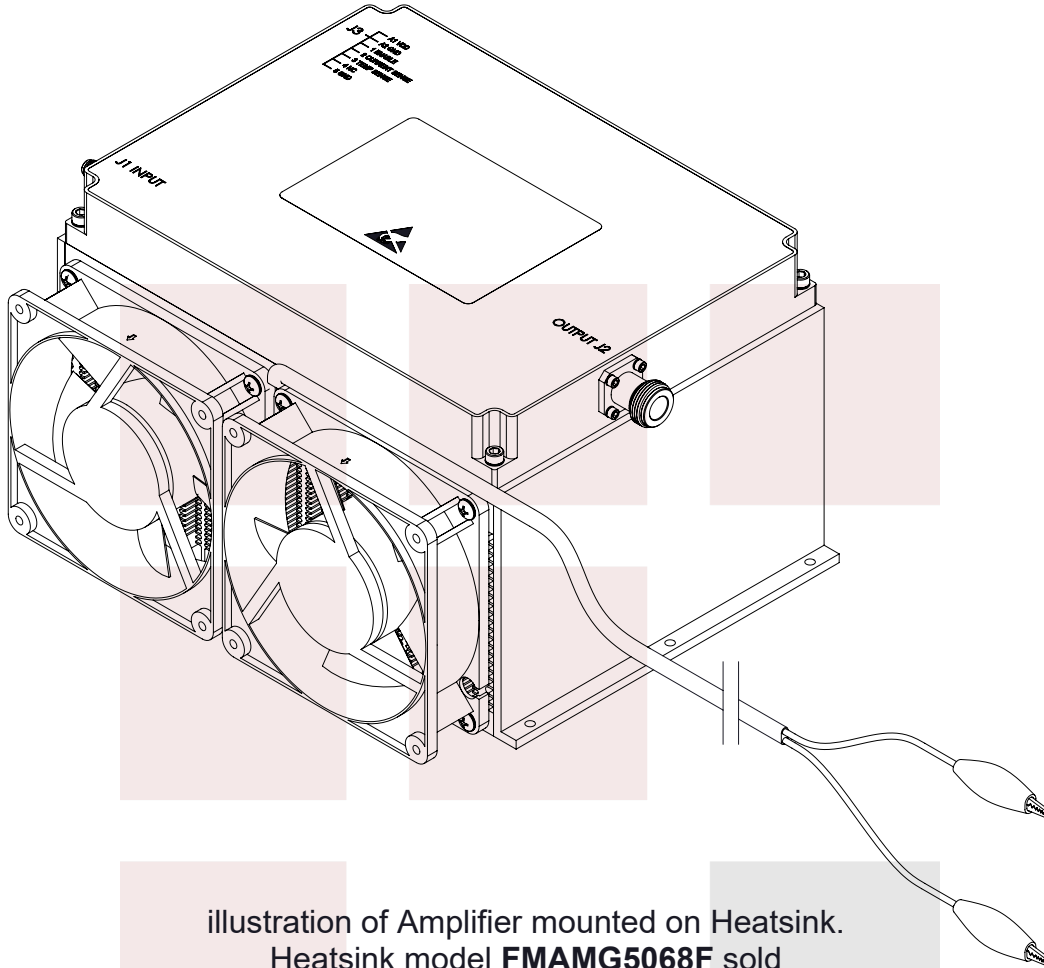
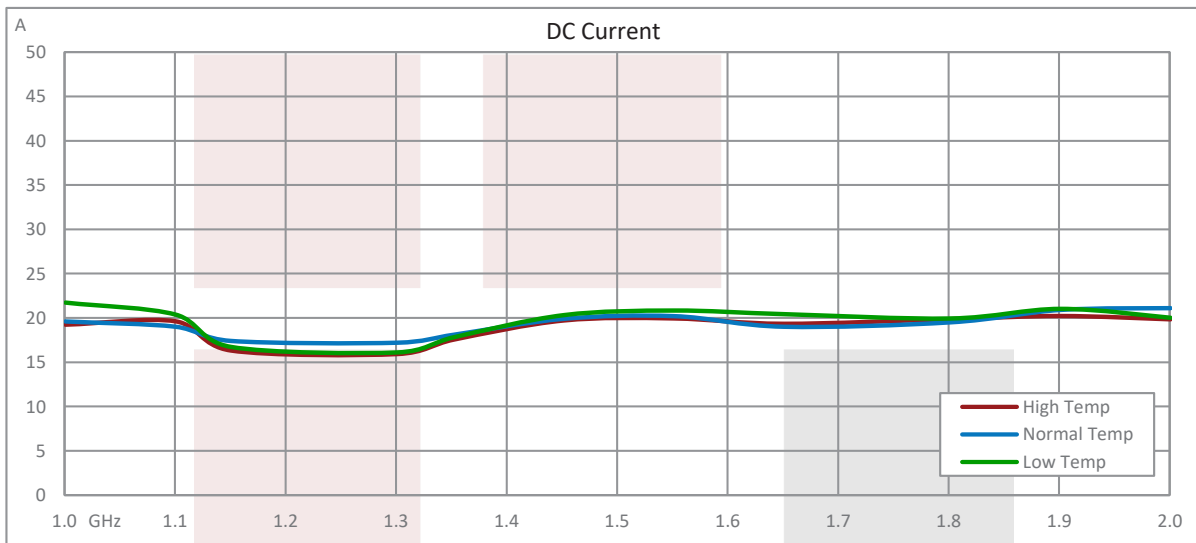
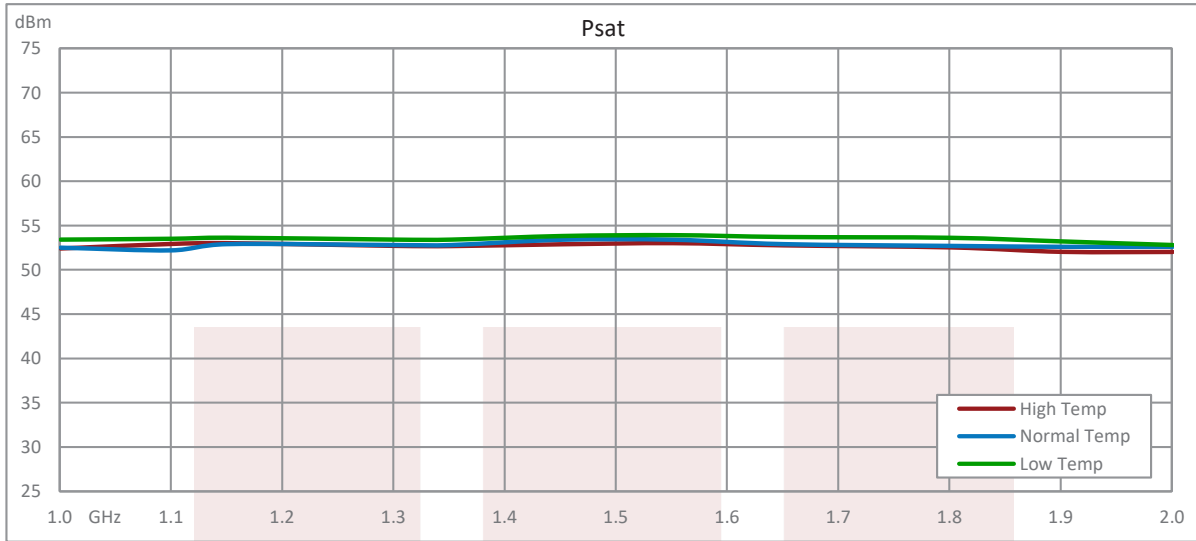
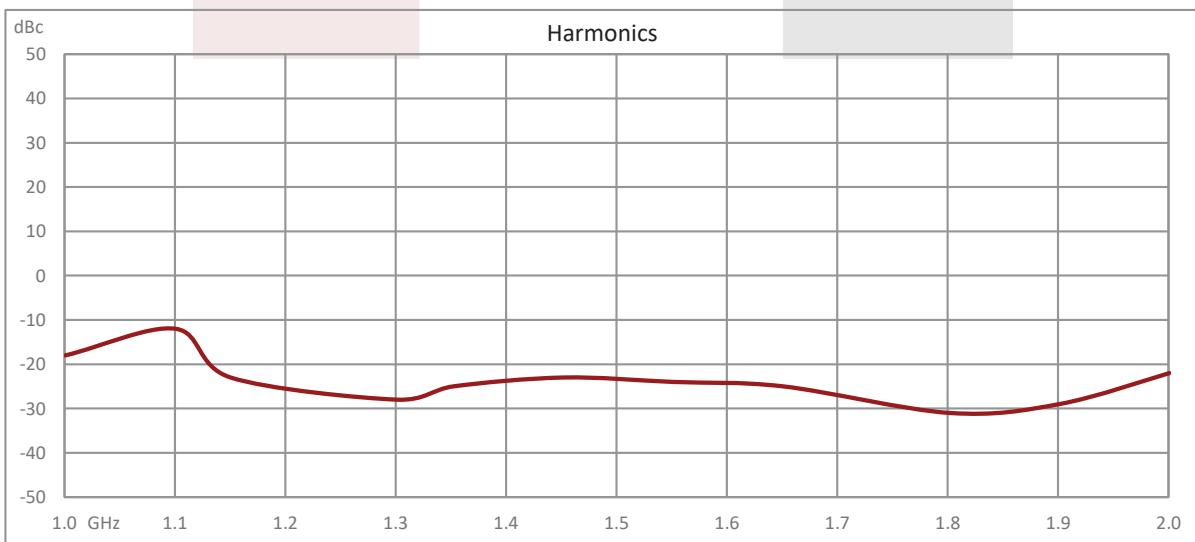
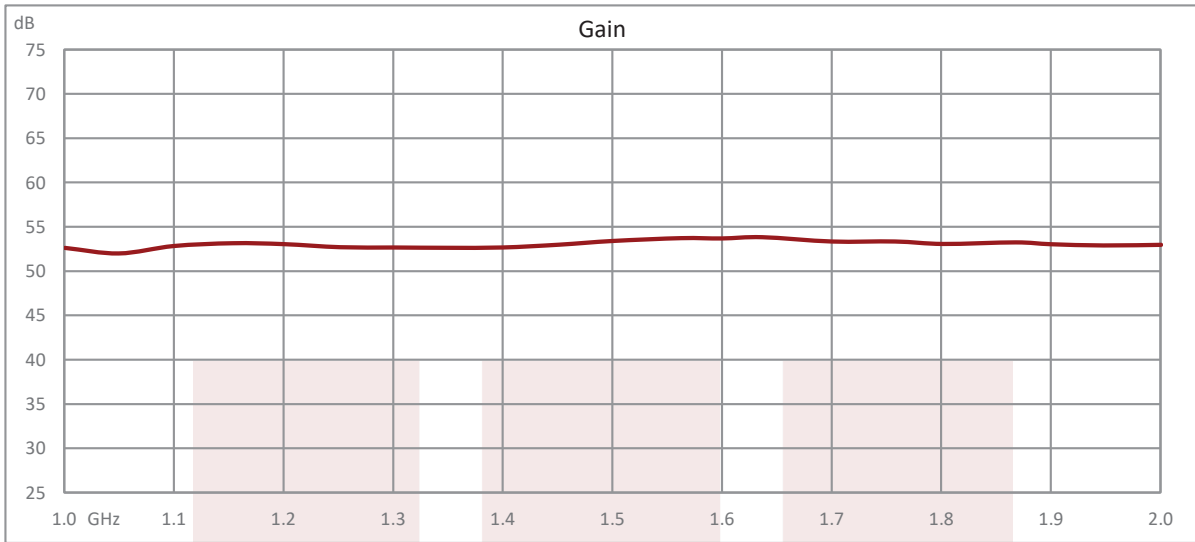


illustration of Amplifier mounted on Heatsink.
Heatsink model **FMAMG5068F** sold
separately.(Picture shown for Reference Only)

Typical Performance Data



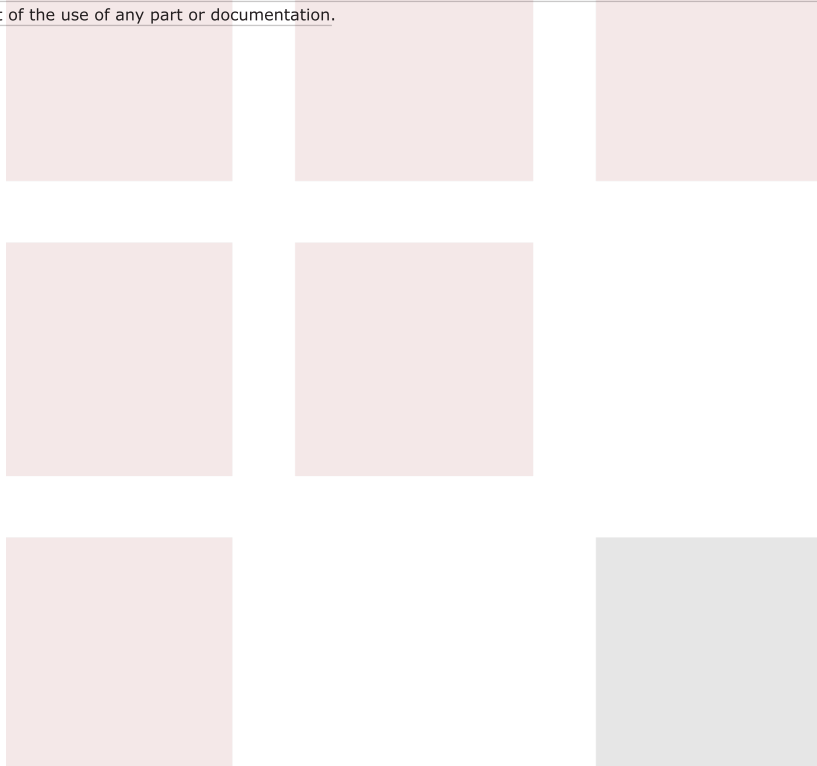


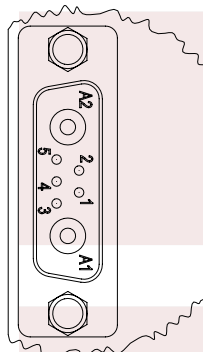
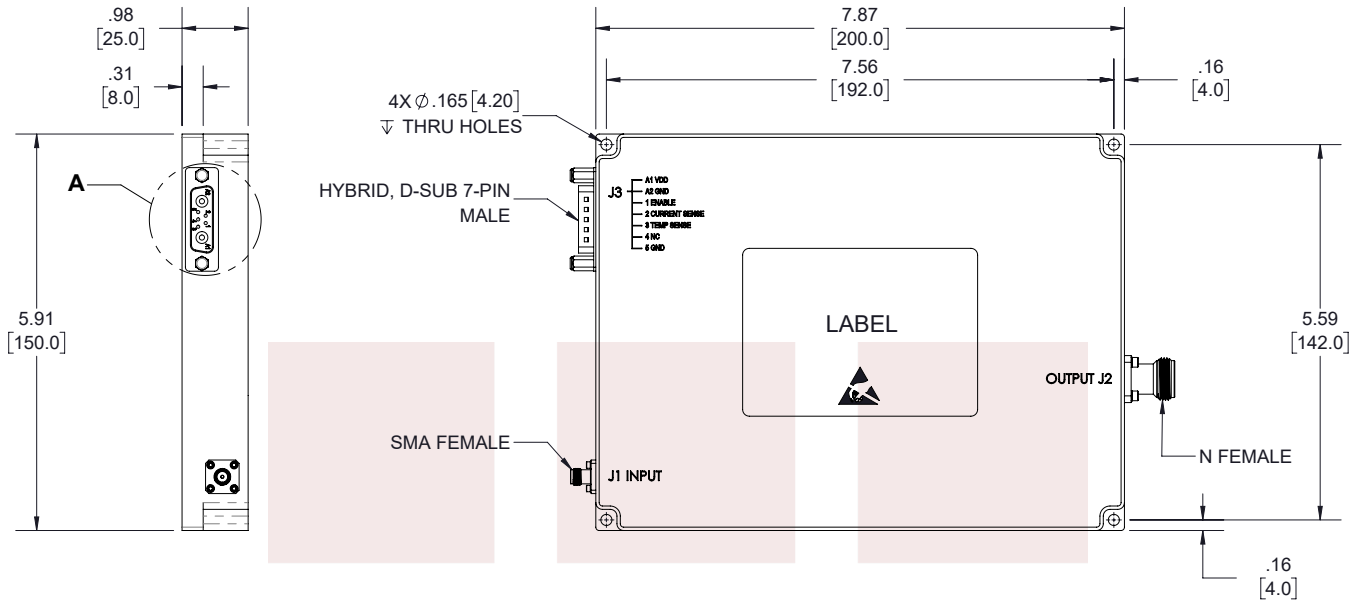
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For additional information on this product, please click the following link: [53 dB Gain High Power GaN Amplifier at 200 Watt Psat Operating from 1 GHz to 2 GHz with SMA Input, Type N Output FMAM5063](#)

URL: <https://www.fairviewmicrowave.com/high-power-amplifier-200watt-fmam5063-p.aspx>

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DETAIL A

HYBRID, D-SUB 7-PIN MALE		
PIN #	DESCRIPTION	SPECIFICATIONS
A1	VDD	28 VDC
A2	GND	Ground
1	ENABLE	Amplifier Enable: TTL Logic High (3.3V) (Internally Pulled-Low)
2	CURRENT SENSE	Analog voltage relative to I_{DD} @ 100mV per Ampere
3	TEMP SENSE	Analog voltage relative to Module's Temperature @ 10 mV/°C
4	NC	No electrical connection
5	GND	Ground

LABEL



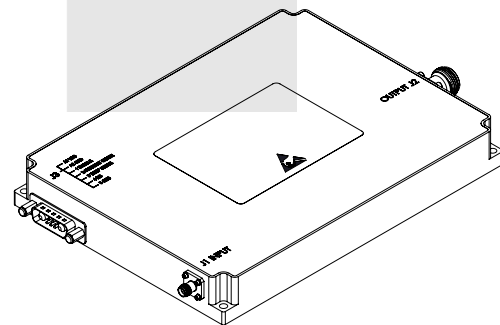
STANDARD TOLERANCES

- .X ±0.2
- .XX ±0.01
- .XXX ±0.005

*STANDARD TOLERANCES APPLY ONLY TO DIMENSIONS IN INCHES

NOTES:

- ADEQUATE HEATSINK REQUIRED.



		NOTES: 1. UNLESS OTHERWISE SPECIFIED ALL DIMENSIONS ARE NOMINAL. 2. ALL SPECIFICATIONS ARE SUBJECT TO CHANGE WITHOUT NOTICE AT ANY TIME. 3. DIMENSIONS ARE IN INCHES [mm].	
TITLE 53 dB Gain High Power GaN Amplifier at 200 Watt Psat Operating from 1 GHz to 2 GHz with SMA Input, Type N Output		DWG NO FMAM5063	
		CAGE CODE 3FKR5	
CAD FILE	07/30/19	SHEET	1 OF 1
SCALE	N/A	SIZE	A
		7361	